

BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC3223TB$

5 V, SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER

DATA SHEET

DESCRIPTION

The μPC3223TB is a silicon monolithic IC designed as IF amplifier for DBS tuners. This IC is manufactured using our 30 GHz fmax UHS0 (<u>Ultra High Speed Process</u>) silicon bipolar process.

FEATURES

- Wideband response : fu = 3.2 GHz TYP. @ 3 dB bandwidth
- Medium output power: Po (sat) = +12.0 dBm @ f = 1.0 GHz
- : Po (sat) = +9.0 dBm @ f = 2.2 GHz
- High linearity : $P_{O(1 dB)} = +6.5 dBm @ f = 1.0 GHz$
- Po (1 dB) = +5.0 dBm @ f = 2.2 GHz
 Power gain : GP = 23.0 dB TYP. @ f = 1.0 GHz
- : G_P = 23.0 dB TYP. @ f = 2.2 GHz
- Supply voltage : Vcc = 4.5 to 5.5 V
- Port impedance : input/output 50 Ω

APPLICATION

• IF amplifiers in DBS converters etc.

ORDERING INFORMATION

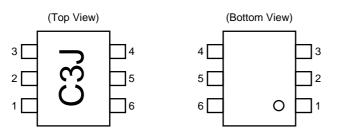
Part Number	Package	Marking	Supplying Form
μPC3223TB-E3	6-pin super minimold	C3J	 Embossed tape 8 mm wide 1, 2, 3 pins face the perforation side of tape Qty 3 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office. Part number for sample order: μ PC3223TB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

PIN CONNECTIONS



Pin No.	Pin Name
1	INPUT
2	GND
3	GND
4	OUTPUT
5	GND
6	Vcc

PRODUCT LINE-UP OF 5 V-BIAS SILICON MMIC MEDIUM OUTPUT AMPLIFIER (TA = +25°C, f = 1 GHz, Vcc = Vout = 5.0 V, Zs = ZL = 50 Ω)

Part No.	fu (GHz)	Po _(sat) (dBm)	G⊦ (dB)	NF (dB)	lcc (mA)	Package	Marking
μPC2708TB	2.9	+10.0	15	6.5	26	6-pin super minimold	C1D
μPC2709TB	2.3	+11.5	23	5.0	25		C1E
μPC2710TB	1.0	+13.5	33	3.5	22		C1F
μPC2776TB	2.7	+8.5	23	6.0	25		C2L
μPC3223TB	3.2	+12.0	23	4.5	19		C3J

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

PIN EXPLANATIONS

PIN No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) ^{Note}	Function and Applications
1	INPUT	_	0.96	Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. A multi-feedback circuits is designed to cancel the deviations of h _{FE} and resistance. This pin must be coupled to signal source with capacitor for DC cut.
4	OUTPUT	Voltage as same as Vcc through external inductor	_	Signal output pin. The inductor must be attached between Vcc and output pins to supply current to the internal output transistors.
6	Vcc	4.5 to 5.5	-	Power suplly pin. Witch biases the internal input transistor. This pin should be externally equipped with bypass capacitor to minimize its impedance.
2 3 5	GND	0	_	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance difference.

Note Pin Voltage is measured at Vcc = 5.0 V

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	Vcc	$T_A = +25^{\circ}C$, Pin 4 and 6	6.0	V
Total Circuit Current	lcc	$T_A = +25^{\circ}C$	40	mA
Power Dissipation	PD	T _A = +85°C Note	270	mW
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	Tstg		–55 to +150	°C
Input Power	Pin	$T_A = +25^{\circ}C$	+10	dBm

Note Mounted on double-sided copper-clad $50 \times 50 \times 1.6$ mm epoxy glass PWB

RECOMMENDED OPERATING RANGE

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc	The same voltage should be applied to pin 4 and 6.	4.5	5.0	5.5	V
Operating Ambient Temperature	TA		-40	+25	+85	°C

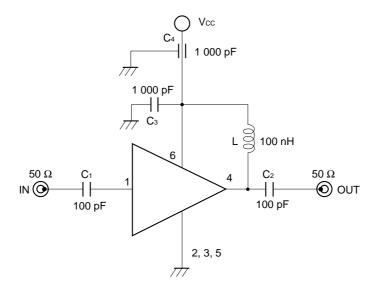
ELECTRICAL CHARACTERISTICS (TA = +25°C, Vcc = Vout = 5.0 V, Zs = ZL = 50 Ω)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	lcc	No input signal	15.0	19.0	24.0	mA
Power Gain	GP	f = 1.0 GHz, P _{in} = -30 dBm	20.5	23.0	25.5	dB
		f = 2.2 GHz, P _{in} = -30 dBm	20.0	23.0	26.0	
Saturated Output Power	Po (sat)	f = 1.0 GHz, P _{in} = -5 dBm	+9.0	+12.0	-	dBm
		f = 2.2 GHz, P _{in} = -5 dBm	+6.0	+9.0	-	
Gain 1 dB Compression Output	Po (1 dB)	f = 1.0 GHz	+4.5	+6.5	-	dBm
Power		f = 2.2 GHz	+3.0	+5.0	-	
Noise Figure	NF	f = 1.0 GHz	_	4.5	6.0	dB
		f = 2.2 GHz	-	4.0	5.5	
Upper Limit Operating Frequency	fu	3 dB down below flat gain at f = 0.1 GHz	2.8	3.2	-	GHz
Isolation	ISL	f = 1.0 GHz, P _{in} = -30 dBm	28.0	33.0	-	dB
		f = 2.2 GHz, P _{in} = -30 dBm	28.0	33.0	-	
Input Return Loss	RLin	f = 1.0 GHz, P _{in} = -30 dBm	9.0	12.0	-	dB
		f = 2.2 GHz, P _{in} = -30 dBm	12.0	17.5	-	
Output Return Loss	RLout	f = 1.0 GHz, P _{in} = -30 dBm	9.0	12.0	-	dB
		f = 2.2 GHz, P _{in} = -30 dBm	9.0	12.0	-	
Gain Flatness	⊿Gp	f = 0.1 to 2.2 GHz	_	±0.9	-	dB

OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY (TA = +25°C, Vcc = Vout = 5.0 V, Zs = ZL = 50 Ω)

Parameter	Symbol	Test Conditions	Reference Value	Unit
Output Intercept Point	OIP₃	f = 1.0 GHz	+17.8	dBm
		f = 2.2 GHz	+14.8	

TEST CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

COMPONENTS OF TEST CIRCUIT FOR MEASURING ELECTRICAL CHARACTERISTICS

	Туре	Value
C1, C2	Chip Capacitor	100 pF
C ₃	Chip Capacitor	1 000 pF
C4	Feed-through Capacitor	1 000 pF
L	Chip Inductor	100 nH

INDUCTOR FOR THE OUTPUT PIN

The internal output transistor of this IC consumes 20 mA, to output medium power. To supply current for output transistor, connect an inductor between the Vcc pin (pin 6) and output pin (pin 4). Select large value inductance, as listed above.

The inductor has both DC and AC effects. In terms of DC, the inductor biases the output transistor with minimum voltage drop to output enable high level. In terms of AC, the inductor makes output-port impedance higher to get enough gain. In this case, large inductance and Q is suitable.

CAPACITORS FOR THE Vcc, INPUT AND OUTPUT PINS

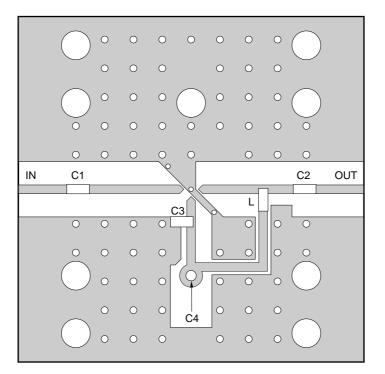
Capacitors of 1000 pF are recommendable as the bypass capacitor for the Vcc pin and the coupling capacitors for the input and output pins.

The bypass capacitor connected to the Vcc pin is used to minimize ground impedance of Vcc pin. So, stable bias can be supplied against Vcc fluctuation.

The coupling capacitors, connected to the input and output pins, are used to cut the DC and minimize RF serial impedance. Their capacitances are therefore selected as lower impedance against a 50 Ω load. The capacitors thus perform as high pass filters, suppressing low frequencies to DC.

To obtain a flat gain from 100 MHz upwards, 1 000 pF capacitors are used in the test circuit. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 10 000 pF. Because the coupling capacitors are determined by equation, $C = 1/(2 \pi R fc)$.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

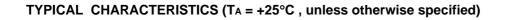


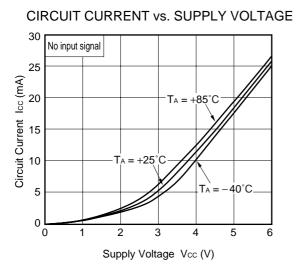
COMPONENT LIST

	Value	
C1, C2	100 pF	
C3, C4	1 000 pF	
L	100 nH	

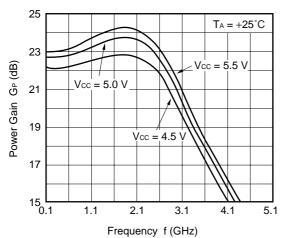
Notes

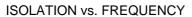
- 1. $30 \times 30 \times 0.4$ mm double sided copper clad polyimide board.
- 2. Back side: GND pattern
- 3. Solder plated on pattern
- 4. oO: Through holes

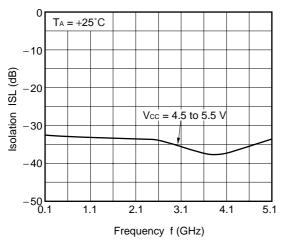




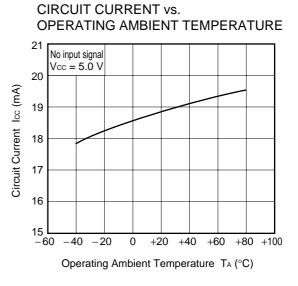
POWER GAIN vs. FREQUENCY



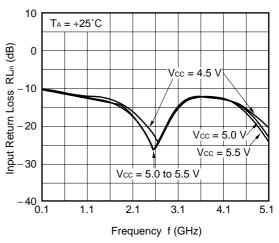




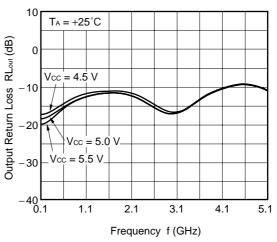
Remark The graphs indicate nominal characteristics.



INPUT RETURN LOSS vs. FREQUENCY



OUTPUT RETURN LOSS vs. FREQUENCY

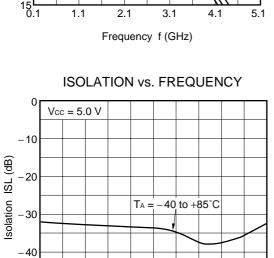


-50L 0.1

1.1

25 Vcc = 5.0 V23 Power Gain GP (dB) $T_A = -40^{\circ}C$ 21 19 T_A = +85°C 17 -25 $T_A =$ റ 15 0.1 1.1 2.1 3.1 4.1 5.1

POWER GAIN vs. FREQUENCY



Frequency f (GHz)

3.1

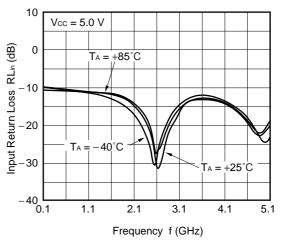
4.1

5.1

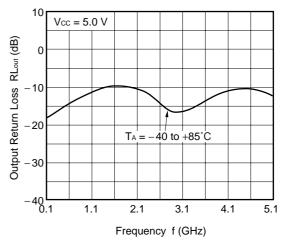
2.1

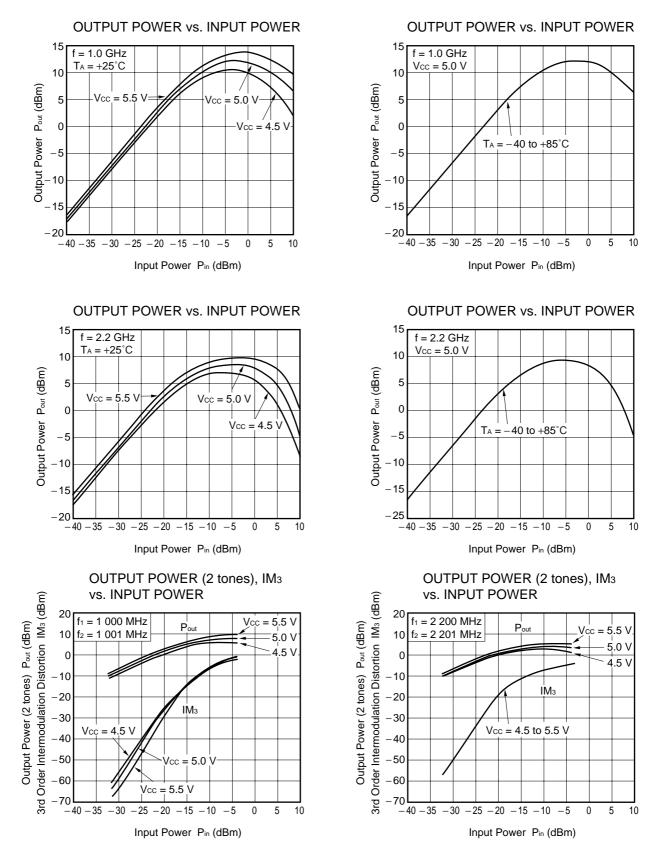
Remark The graphs indicate nominal characteristics.

INPUT RETURN LOSS vs. FREQUENCY



OUTPUT RETURN LOSS vs. FREQUENCY

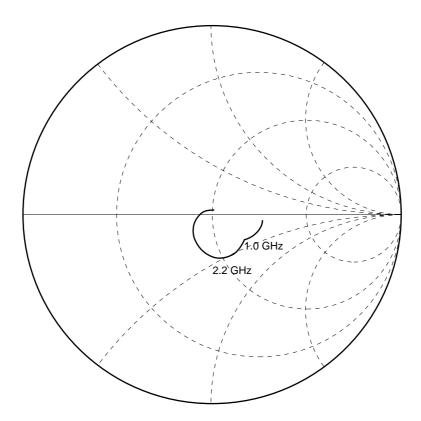




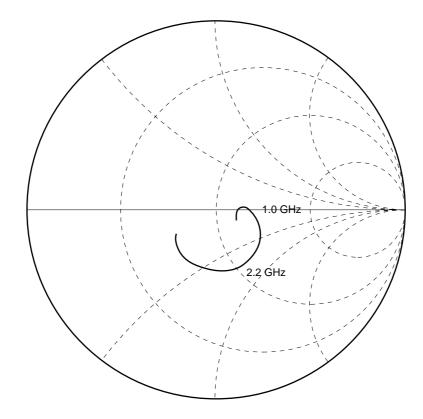
Remark The graphs indicate nominal characteristics.

S-PARAMETERS (TA = +25°C, Vcc = Vout = 5.0 V)

S11-FREQUENCY



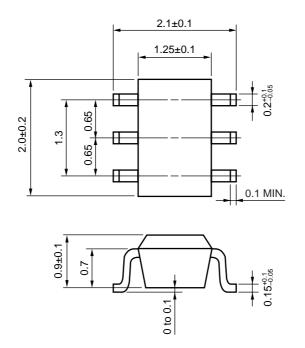
S22-FREQUENCY



Data Sheet PU10491EJ01V0DS

PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation). All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.
- (4) The inductor must be attached between Vcc and output pins. The inductance value should be determined in accordance with desired frequency.
- (5) The DC cut capacitor must be each attached to input and output pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) Time at peak temperature Preheating temperature (package surface temperature) Maximum number of flow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 120°C or below : 1 time : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (pin temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	H\$350

Caution Do not use different soldering methods together (except for partial heating).

- The information in this document is current as of May, 2004. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:

"Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation, NEC Compound Semiconductor Devices, Ltd. and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

M8E 00.4-0110

▶ For further information, please contact

 NEC Compound Semiconductor Devices, Ltd.
 http://www.ncsd.necel.com/

 E-mail: salesinfo@ml.ncsd.necel.com (sales and general)
 techinfo@ml.ncsd.necel.com (technical)

 5th Sales Group, Sales Division TEL: +81-44-435-1588
 FAX: +81-44-435-1579

NEC Compound Semiconductor Devices Hong Kong Limited

 E-mail: ncsd-hk@elhk.nec.com.hk (sales, technical and general)

 Hong Kong Head Office
 TEL: +852-3107-7303
 FAX: +852-3107-7309

 Taipei Branch Office
 TEL: +886-2-8712-0478
 FAX: +886-2-2545-3859

 Korea Branch Office
 TEL: +82-2-558-2120
 FAX: +82-2-558-5209

NEC Electronics (Europe) GmbH http://www.ee.nec.de/ TEL: +49-211-6503-0 FAX: +49-211-6503-1327

California Eastern Laboratories, Inc. http://www.cel.com/ TEL: +1-408-988-3500 FAX: +1-408-988-0279